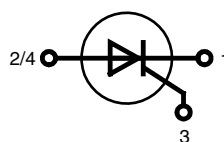
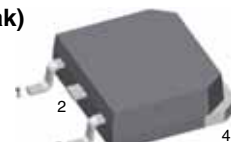


High Voltage Phase Control Thyristor

$$V_{\text{DRM}} = 2500 \text{ V}$$

$$I_{\text{TSM}} = 200 \text{ A}$$


TO-268 AA (D³Pak)


4 = Backside = Anode

Thyristor				
Symbol	Conditions	Maximum Ratings		
V_{DRM}		2500	V	
V_{DSM}		2500	V	
$V_{\text{RRM}} / \text{RSM}$		1650	V	
I_{TSM}	sine 180°; $t = 10 \text{ ms}$; $V_{\text{R}} = 0 \text{ V}$; $T_{\text{VJ}} = 25^{\circ}\text{C}$	200	A	
$(di/dt)_{\text{cr}}$	$f = 50 \text{ Hz}$; $t_{\text{p}} = 200 \text{ }\mu\text{s}$; $V_{\text{D}} = 2000 \text{ V}$ $di_{\text{G}}/dt = 0.45 \text{ A}/\mu\text{s}$; $I_{\text{G}} = 0.45 \text{ A}$ non repetitive; $I_{\text{T}} = 45 \text{ A}$	150	A/ μs	
$(dv/dt)_{\text{cr}}$	$V_{\text{D}} = 2200 \text{ V}$ $R_{\text{GK}} = \infty$; method 1 (linear voltage rise)	5000	V/ μs	
Symbol	Conditions	Characteristic Values		
		min.	max.	
V_{T}	$I_{\text{T}} = 45 \text{ A}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$		3.0	V
V_{GT}	$V_{\text{D}} = 6 \text{ V}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$		2.5	V
I_{GT}			250	mA
V_{GD}	$V_{\text{D}} = \frac{2}{3} V_{\text{DRM}}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$		0.2	V
I_{GD}			5	mA
I_{L}	$t_{\text{p}} = 10 \text{ }\mu\text{s}$; $V_{\text{D}} = 6 \text{ V}$ $I_{\text{G}} = 0.45 \text{ A}$; $di_{\text{G}}/dt = 0.45 \text{ A}/\mu\text{s}$ $T_{\text{VJ}} = 0^{\circ}\text{C}$		700	mA
I_{H}	$V_{\text{D}} = 6 \text{ V}$; $R_{\text{GK}} = \infty$ $T_{\text{VJ}} = 0^{\circ}\text{C}$ $T_{\text{VJ}} = 70^{\circ}\text{C}$	55	300	mA mA
t_{q}	$I_{\text{T}} = 20 \text{ A}$; $t_{\text{p}} = 300 \text{ }\mu\text{s}$; $di/dt = -20 \text{ A}/\mu\text{s}$ $V_{\text{R}} = 10 \text{ V}$; $dv/dt = 20 \text{ V}/\mu\text{s}$ $V_{\text{D}} = 800 \text{ V}$ $T_{\text{VJ}} = 70^{\circ}\text{C}$		100	μs
$I_{\text{RRM}} / \text{DRM}$	$V_{\text{R}} = V_{\text{RRM}}$; $V_{\text{D}} = V_{\text{DRM}}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$ $T_{\text{VJ}} = 70^{\circ}\text{C}$		50 200	μA μA
$I_{\text{DSM}} / \text{RSM}$	$V_{\text{R}} = V_{\text{RSM}}$; $V_{\text{D}} = V_{\text{DSM}}$ $T_{\text{VJ}} = 70^{\circ}\text{C}$		2	mA
R_{thJC}			0.80	K/W

Features

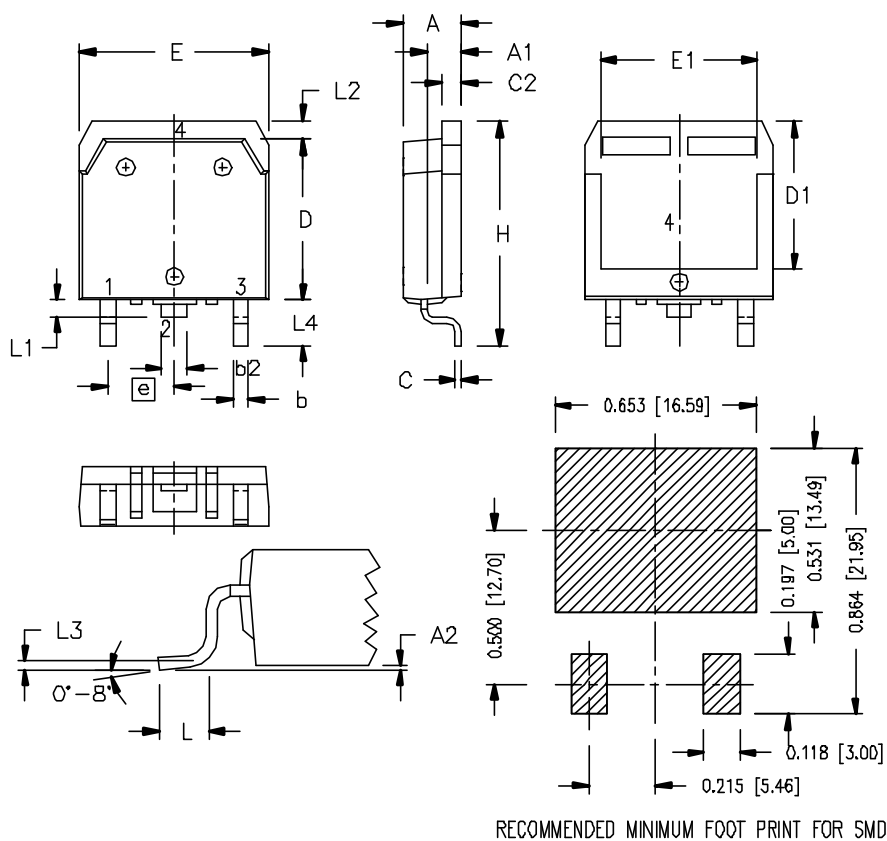
- high voltage thyristor
 - for line frequency
 - chip technology for long term stability
 - planar glass passivated
- International standard package
JEDEC TO-268
- Epoxy meets UL 94V-0

Applications

- controlled rectifiers
 - power supplies
 - drives
- AC switches
- capacitor discharge control
 - flash tubes
 - X-ray and laser generators

Component				
Symbol	Conditions	Maximum Ratings		
T _{VJ}		-10 ... +70	°C	
T _{stg}		-40 ... +70	°C	
F _C	Mounting force with clip	20...120	N	

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
R _{thCH}	with heatsink compound		0.15		K/W
Weight			5		g



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.90	5.10	0.193	0.201
A1	2.70	2.90	0.106	0.114
A2	0.02	0.25	0.001	0.100
b	1.15	1.45	0.045	0.057
b2	1.90	2.10	0.075	0.083
C	0.40	0.65	0.016	0.026
C2	1.45	1.60	0.057	0.063
D	13.80	14.00	0.543	0.551
D1	12.40	12.70	0.488	0.500
E	15.85	16.05	0.624	0.632
E1	13.30	13.60	0.524	0.535
e	5.45 BSC		0.215 BSC	
H	18.70	19.10	0.736	0.752
L	2.40	2.70	0.094	0.106
L1	1.20	1.40	0.047	0.055
L2	1.00	1.15	0.039	0.045
L3	0.25 BSC		0.100 BSC	
L4	3.80	4.10	0.150	0.161

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[IXYS:](#)

[CS20-25moT1](#)